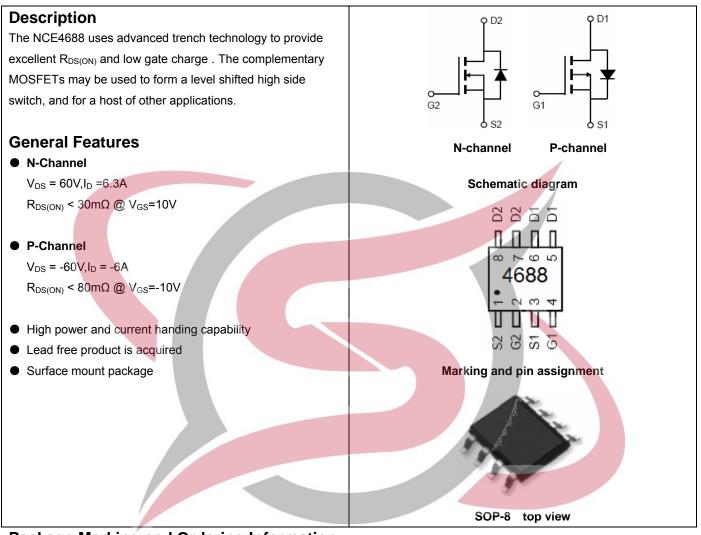




N and P-Channel Enhancement Mode Power MOSFET



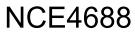
Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
4688	NCE4688	SOP-8	Ø330mm	12mm	2500 units

Absolute Maximum Ratings (T_A=25[°]Cunless otherwise noted)

		ELEC	TRO	NIC		
Parameter		Symbol	N-Channel	P-Channel	Unit	
Drain-Source Voltage		V _{DS}	60	-60	V	
Gate-Source Voltage	V _{GS}	±20	±20	V		
Continuous Drain Current	T _A =25℃	1-	6.3	-6	А	
	T _A =100℃	l _D	4.5	-4.2	A	
Pulsed Drain Current (Note 1)		I _{DM}	40	-25	А	
Maximum Power Dissipation	T _A =25℃	PD	2.0	2.0	W	
Operating Junction and Storage Ter	T _J ,T _{STG}	-55 To 150	-55 To 150	°C		





Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note2)	R _{0JA}	N-Ch	62.5	°C/W
Thermal Resistance, Junction-to-Ambient (Note2)	$R_{ extsf{ heta}JA}$	P-Ch	62.5	°C/W

N-CH Electrical Characteristics (T_A=25°C unless otherwise noted)

Symbol	Condition	Min	Тур	Max	Unit		
BV _{DSS}	V _{GS} =0V I _D =250µA	60	-	-	V		
I _{DSS}	V _{DS} =60V,V _{GS} =0V	-	-	1	μA		
I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA		
			1				
V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250µA	1.2	1.6	2.5	V		
R _{DS(ON)}	V _{GS} =10V, I _D =6A	-	26	30	mΩ		
g fs	V _{DS} =5V,I _D =6A	15	-	-	S		
C _{lss}		-	500	-	PF		
C _{oss}		-	60	-	PF		
C _{rss}	F=1.0MHZ	-	25	-	PF		
Switching Characteristics (Note 4)							
t _{d(on)}		-	5	-	nS		
tr	V _{DD} =30V, R _L =4.7Ω	-	2.6		nS		
t _{d(off)}	V _{GS} =10V,R _{GEN} =3Ω	-	16.1	-	nS		
t _f		-	2.3	-	nS		
Qg		-	25	_	nC		
Qgs		-	4.5	-	nC		
Q _{gd}	V _{GS} =10V	-	6.5	-	nC		
,		•					
V _{SD}	V _{GS} =0V,I _S =6A	-	0.8	1.2	V		
	IDSS IGSS VGS(th) RDS(ON) GFS Cliss Coss Crss td(on) tr td(off) tf Qg Qgd	$\begin{tabular}{ c c c c c } \hline I_{DSS} & V_{DS}=60V, V_{GS}=0V \\ \hline I_{GSS} & V_{GS}=\pm 20V, V_{DS}=0V \\ \hline & V_{GS(th)} & V_{DS}=V_{GS}, I_{D}=250 \mu A \\ \hline & V_{DS}=0V, I_{D}=6A \\ \hline & V_{DS}=5V, I_{D}=6A \\ \hline & V_{DS}=5V, I_{D}=6A \\ \hline & V_{DS}=15V, V_{GS}=0V, \\ \hline & C_{rss} & F=1.0MHz \\ \hline & C_{rss} & F=1.0MHz \\ \hline & I_{d(on)} & V_{DD}=30V, R_{L}=4.7\Omega \\ \hline & V_{GS}=10V, R_{GEN}=3\Omega \\ \hline & I_{f} & V_{DS}=15V, I_{D}=6A, \\ \hline & V_{GS}=10V \\ \hline & Q_{gd} & V_{DS}=15V, I_{D}=6A, \\ \hline & V_{GS}=10V \\ \hline & V_{GS}=10V \\ \hline & V_{GS}=10V \\ \hline \end{tabular}$	$\begin{array}{c c c c c c c c c } I_{DSS} & V_{DS}=60V, V_{GS}=0V & - \\ I_{GSS} & V_{GS}=\pm 20V, V_{DS}=0V & - \\ \hline \\ & & & \\ \hline \\ \\ & & & \\ \hline \\ \\ \\ & & & \\ \hline \\ \\ \\ \\$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $		

ELECTRONIC





P-CH Electrical Characteristics (T_A=25[°]C unless otherwise noted)

P-CH Electrical Characteristics			<u> </u>	T		11
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			T	n		
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-60	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-60V, V_{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-1.5	-2.6	-3.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V_{GS} =-10V, I _D =-5A	-	64	80	mΩ
Forward Transconductance	g fs	V _{DS} =-15V,I _D =-5A	16	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	Ciss		-	1450	-	PF
Output Cap <mark>acitanc</mark> e	Coss	V _{DS} =-20V,V _{GS} =0V, F=1.0MHz		145	-	PF
Reverse Transfer Capacitance	Crss	F=1.0WHZ	-	110	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	8	-	nS
Turn-on Rise Time	tr	V_{DD} =-30V, ,RL=30 Ω	-	9	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-10V, R_{GEN} =6 Ω	-	65	-	nS
Turn-Off Fall Time	tf		-	30	-	nS
Total Gate Charge	Qg		-	26	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =-30V,I _D =-5A, V _{GS} =-10V	-	4.5	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =-10V	-	7	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-6A	-	-	-1.2	V
Diode Forward Current (Note 2)	Is		-	-	-6	А

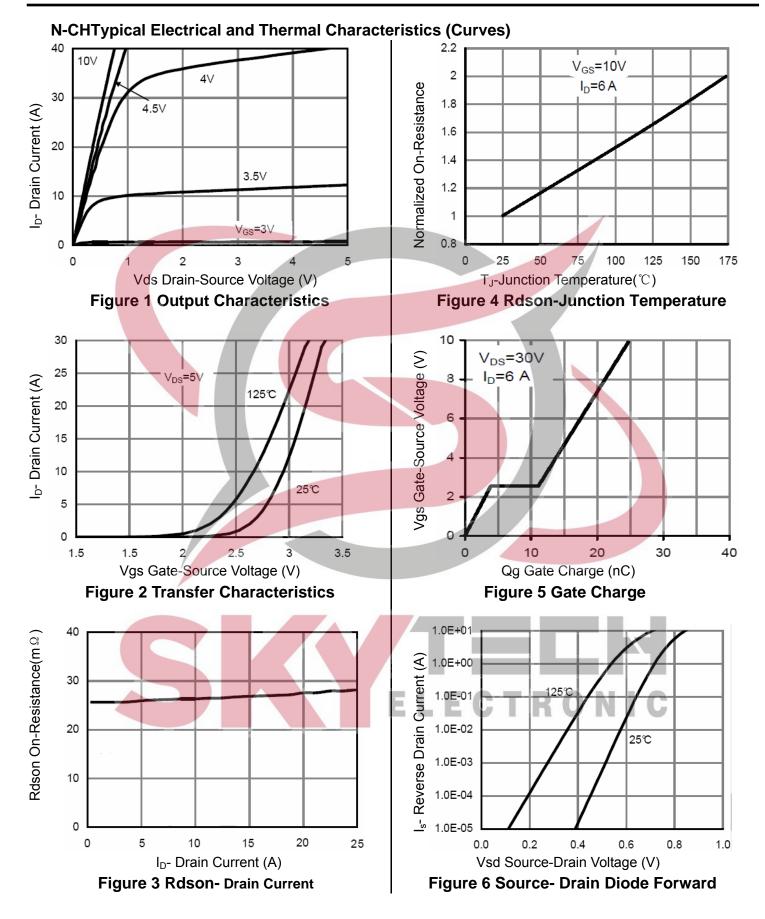
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production

ELECTRO



NCE4688





http://www.ncepower.com



NCE4688

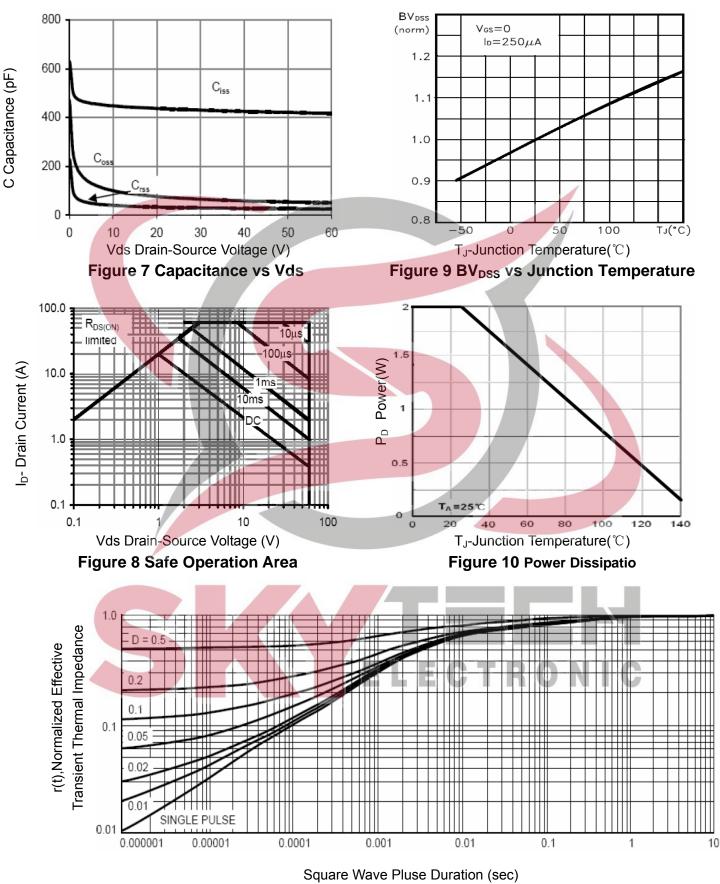
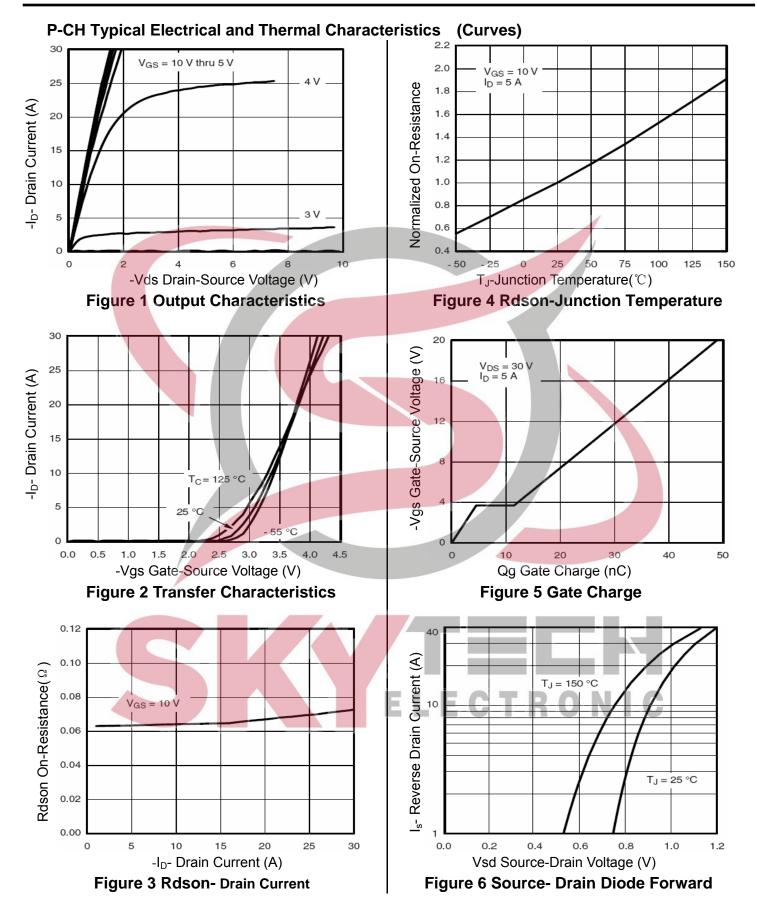


Figure 11 Normalized Maximum Transient Thermal Impedance



NCE4688

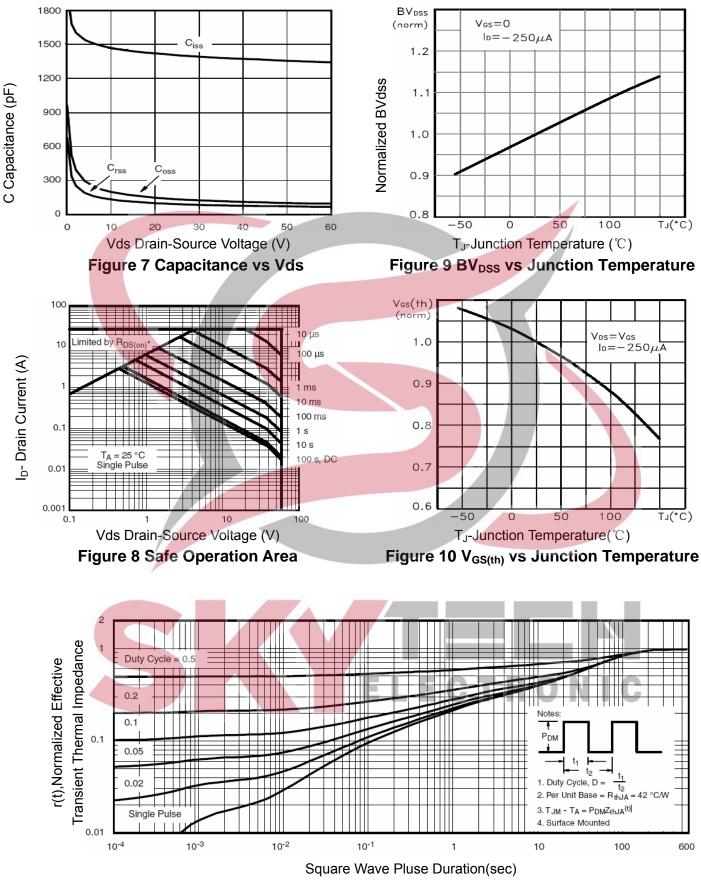




http://www.ncepower.com



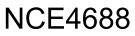
NCE4688



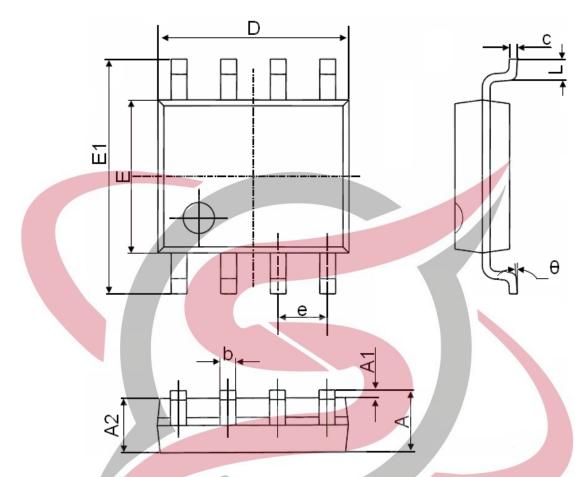




http://www.ncepower.com



SOP-8 Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
e	1.270(BSC)		0.050(BSC)		
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	







Attention

- Any and all NCE power products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your NCE power representative nearest you before using any NCE power products described or contained herein in such applications.
- NCE power assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all NCE power products described or contained herein.
- Specifications of any and all NCE power products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- NCE power Semiconductor CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all NCE power products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of NCE power Semiconductor CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. NCE power believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the NCE power product that you intend to use.
- This catalog provides information as of Sep.2010. Specifications and information herein are subject to change without notice.

SKYTECH